

NEW MEAM POTENTIALS FOR THE Al, Si, Mg, Cu, AND Fe ALLOY SYSTEM

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OUTLINE

- **Modified EAM (MEAM)**
- **Issues for multi-component systems**
- **Binary alloys calculations**
- **A few applications to the multi-component system**

WE ARE ALL FAMILIAR WITH THE EMBEDDED ATOM METHOD FORMALISM

embedding energy

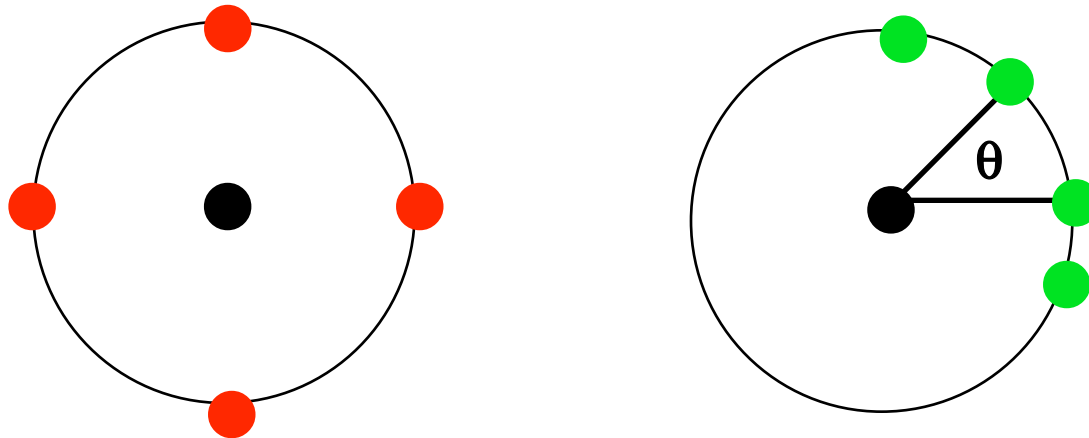
host electron density

pair interaction

$$E = \sum_i \left(F_i(\bar{\rho}_i) + \frac{1}{2} \sum_{j \neq i} \phi_{ij}(R_{ij}) \right)$$

COMPLEX MATERIALS REQUIRE THE ADDITION OF ANGULAR FORCES

- EAM uses a linear superposition of spherically averaged electron densities
- MEAM allows the background electron density to depend on the local symmetry



MODIFIED EMBEDDED ATOM METHOD (MEAM)

Universal Binding Energy Relationship UBER

$$E^u(R) = -E_c \left(1 + a^* + \delta a^{*3} \frac{r_e}{R} \right) e^{-a^*}$$

$$a^* = \alpha \left(\frac{R}{r_e} - 1 \right) \quad \alpha^2 = \frac{9\Omega B}{E_c}$$

Background Electron Density

$$\bar{\rho} = \rho^{(0)} \sqrt{1 + \Gamma}$$

$$\Gamma = \sum_{l=1}^3 t^{(l)} \left(\rho^{(l)} / \rho^{(0)} \right)^2$$

$$\rho_k^{(l)2} = \sum_i \rho_l(R_{ik}) \sum_j \rho_l(R_{kj}) P_l^0(\cos(\theta_{ikj}))$$

$$\rho_l = e^{-b^*} S \quad b^* = \beta^{(l)} \left(\frac{\kappa}{r_e} - 1 \right)$$

Embedding Function

$$F(\bar{\rho}) = A E_c \bar{\rho} \ln \bar{\rho}$$

Pair Potential

$$\phi(R) = \frac{2}{Z} \{ E^u(R) - F(\bar{\rho}^0(R)) \} S$$

A FOUR PARAMETER MEAM MODEL HAS BEEN DEVELOPED FOR BINARY ALLOYS

- Use previously developed functions for elements A and B
- Electron density ratio (A/B)
- Universal EOS for reference structure, AB (**B1**)

$$E = -E_0 \left(1 + a^*\right) e^{-a^*} \quad a^* = \alpha \left(\frac{r}{r_0} - 1 \right)$$

-nearest neighbor distance, r_0 (Å)

-distance scaling, α

-formation energy, E_0 (eV/atom)

- Angular screening

ELECTRON DENSITY SCALING PARAMETER IS LOST FOR MULTI- COMPONENT SYSTEMS

- For A-B system: ρ_B^0 / ρ_A^0
- For A-C system: ρ_C^0 / ρ_A^0
- For B-C system: ρ_C^0 / ρ_B^0

- For A-B-C system: ρ_B^0 / ρ_A^0 , ρ_C^0 / ρ_A^0
- For an N-component system
 - ✓ $N(N-1)/2$ binaries
 - ✓ $3N(N-1)/2 + (N-1)$ alloy parameters
- Angular screening
 - ✓ $8N(N-1)/2$ alloy parameters

SINGLE ELEMENT PARAMETERS

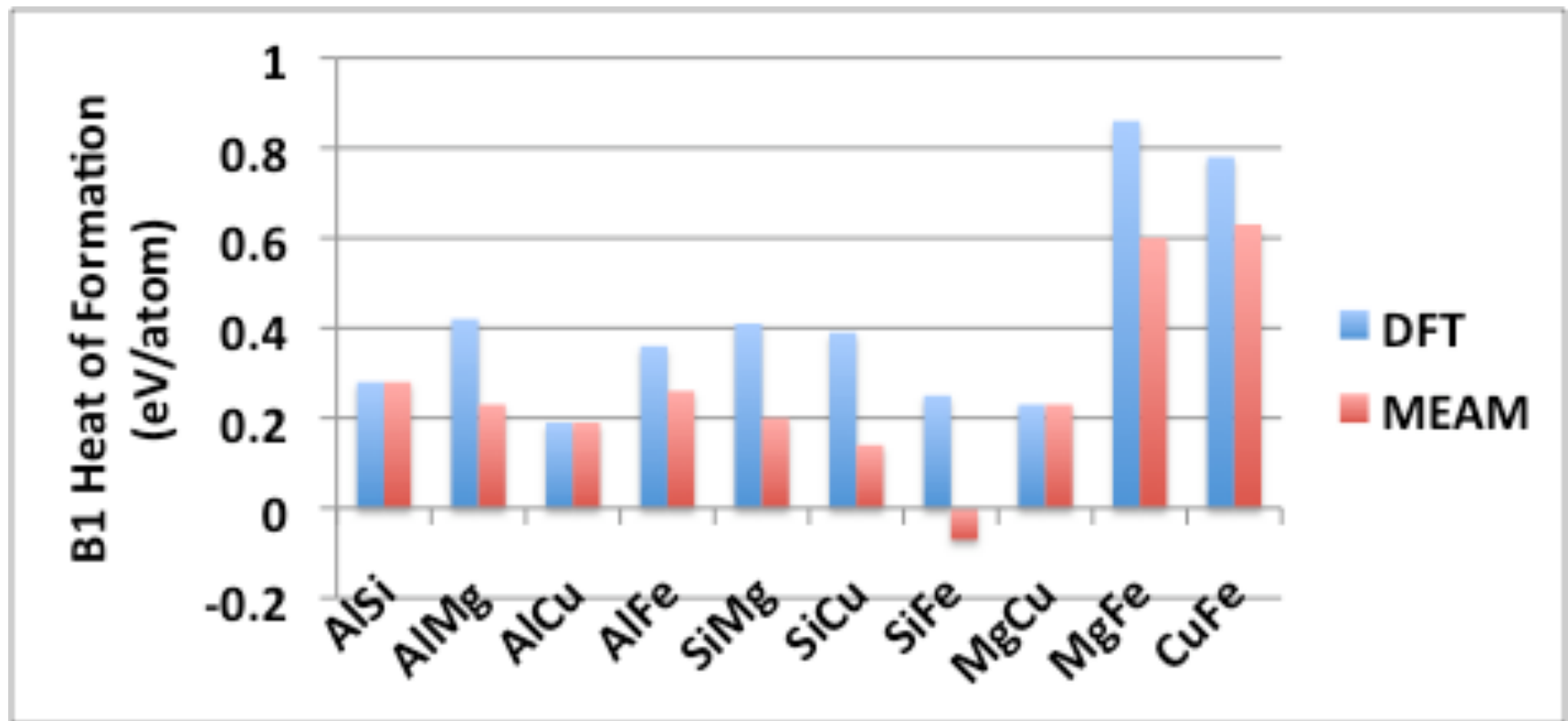
elem.	E_c [eV]	a_0 [Å]	A	α	$\beta^{(0)}$	$\beta^{(1)}$	$\beta^{(2)}$	$\beta^{(3)}$	$t^{(0)}$	$t^{(1)}$	$t^{(2)}$	$t^{(3)}$	C_{\min}	C_{\max}	ρ_0
Al	3.353	4.05	1.07	4.64	2.04	1.5	6.0	1.5	1.0	4.00	-2.30	8.01	0.8	2.8	1.0
Si	4.63	5.431	1.00	4.87	4.4	5.5	5.5	5.5	1.0	2.05	4.47	-1.80	2.0	2.8	2.2
Mg	1.51	3.194	0.8	5.52	4.0	3.0	0.2	1.2	1.0	10.04	9.49	-4.3	0.8	2.8	0.63
Cu	3.54	3.62	1.07	5.11	3.634	2.2	6.0	2.2	1.0	4.91	2.49	2.95	0.8	2.8	1.1
Fe	4.28	2.851	0.555	5.027	3.5	2.0	1.0	1.0	1.0	-1.6	12.5	-1.4	0.8	1.9	1.0

For Fe the δ parameter in the EOS was used

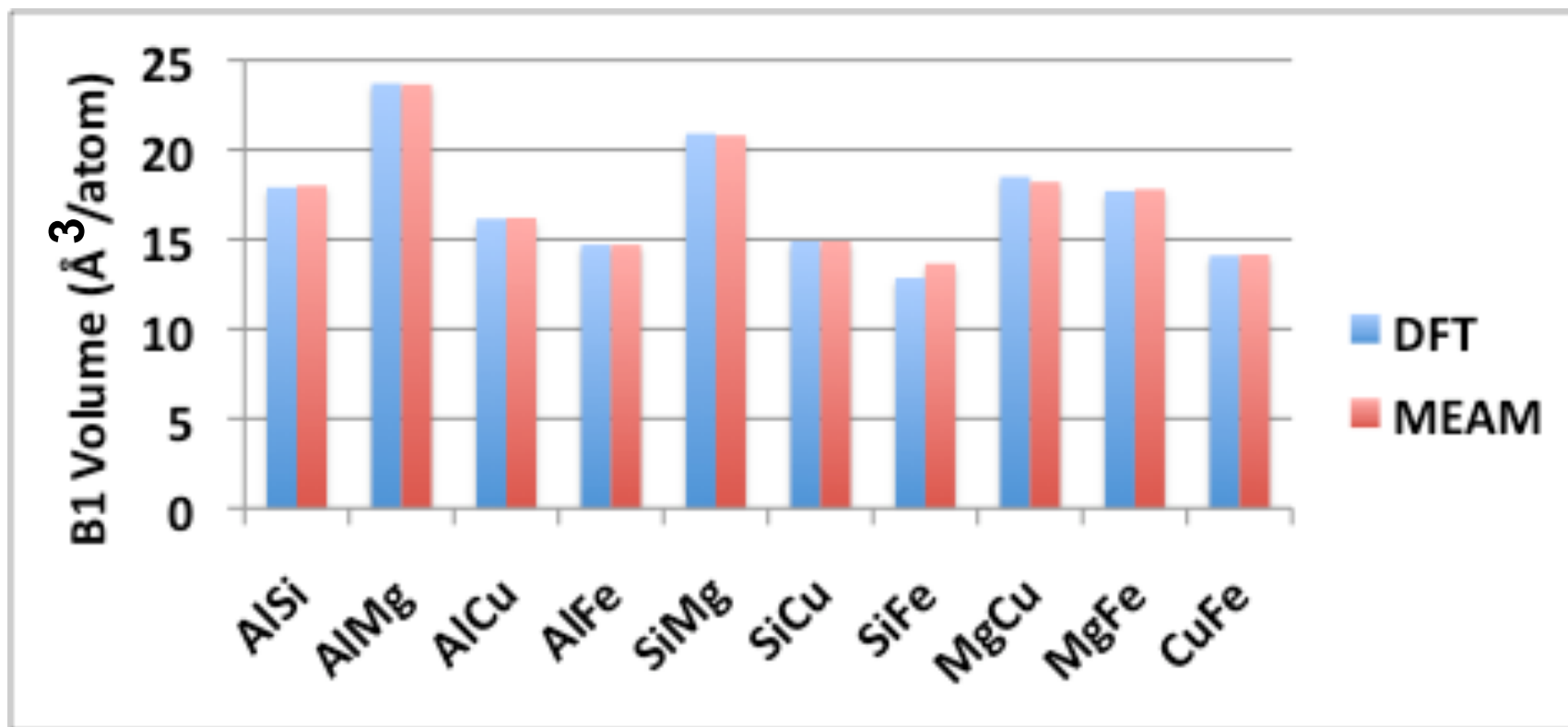
ALLOY PARAMETERS

X	Y	ΔH_{B1}^{XY} [eV]	r_e [Å]	α	C_{min}^{XYX}	C_{max}^{XYX}	C_{min}^{YXY}	C_{max}^{YXY}	C_{min}^{XXY}	C_{max}^{XXY}	C_{min}^{XYY}	C_{max}^{XYY}
Al	Si	0.28	2.62	4.56	0.5	2.8	2.0	2.8	2.0	2.8	2.0	2.8
Al	Mg	0.23	2.87	4.52	2.0	2.8	0.0	2.8	2.0	2.8	0.0	2.8
Al	Cu	0.19	2.53	4.65	0.0	2.8	2.0	2.8	2.0	2.8	2.0	2.8
Al	Fe	0.26	2.45	4.64	0.9	2.8	0.1	2.8	2.0	2.8	2.0	2.8
Si	Mg	0.20	2.75	4.73	1.0	2.8	1.0	2.8	2.0	2.8	2.0	2.8
Si	Cu	0.14	2.46	4.74	0.0	2.8	0.0	2.8	2.0	2.8	2.0	2.8
Si	Fe	-0.07	2.39	5.17	1.0	2.8	1.0	2.8	2.0	2.8	0.0	2.8
Mg	Cu	0.23	2.63	4.70	2.0	2.8	0.0	2.8	2.0	2.8	2.0	2.8
Mg	Fe	0.60	2.61	4.96	0.65	2.8	0.0	2.8	2.0	2.8	2.0	2.8
Cu	Fe	0.63	2.42	5.21	2.0	2.8	0.0	2.8	2.0	2.8	2.0	2.8

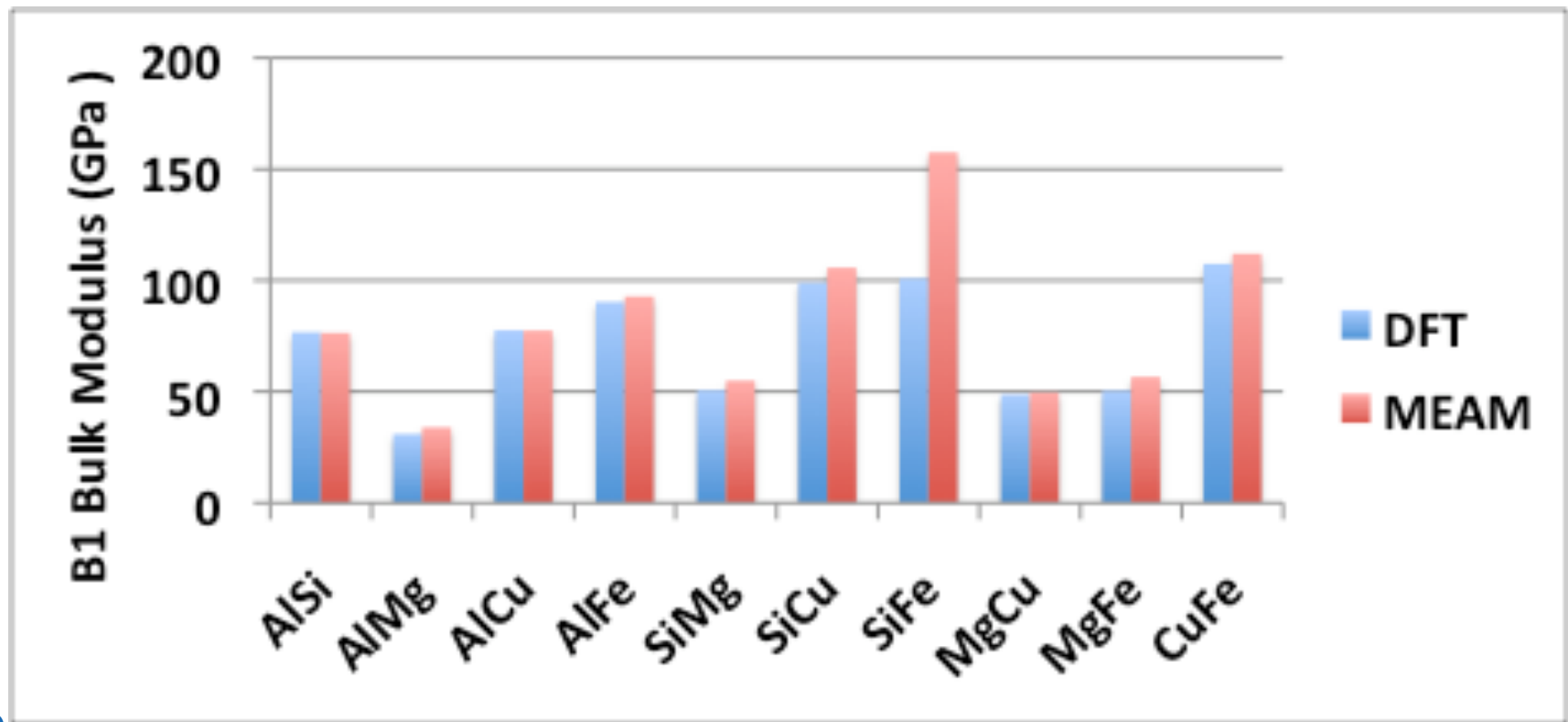
MEAM COMPARISON TO DFT DATA BASE



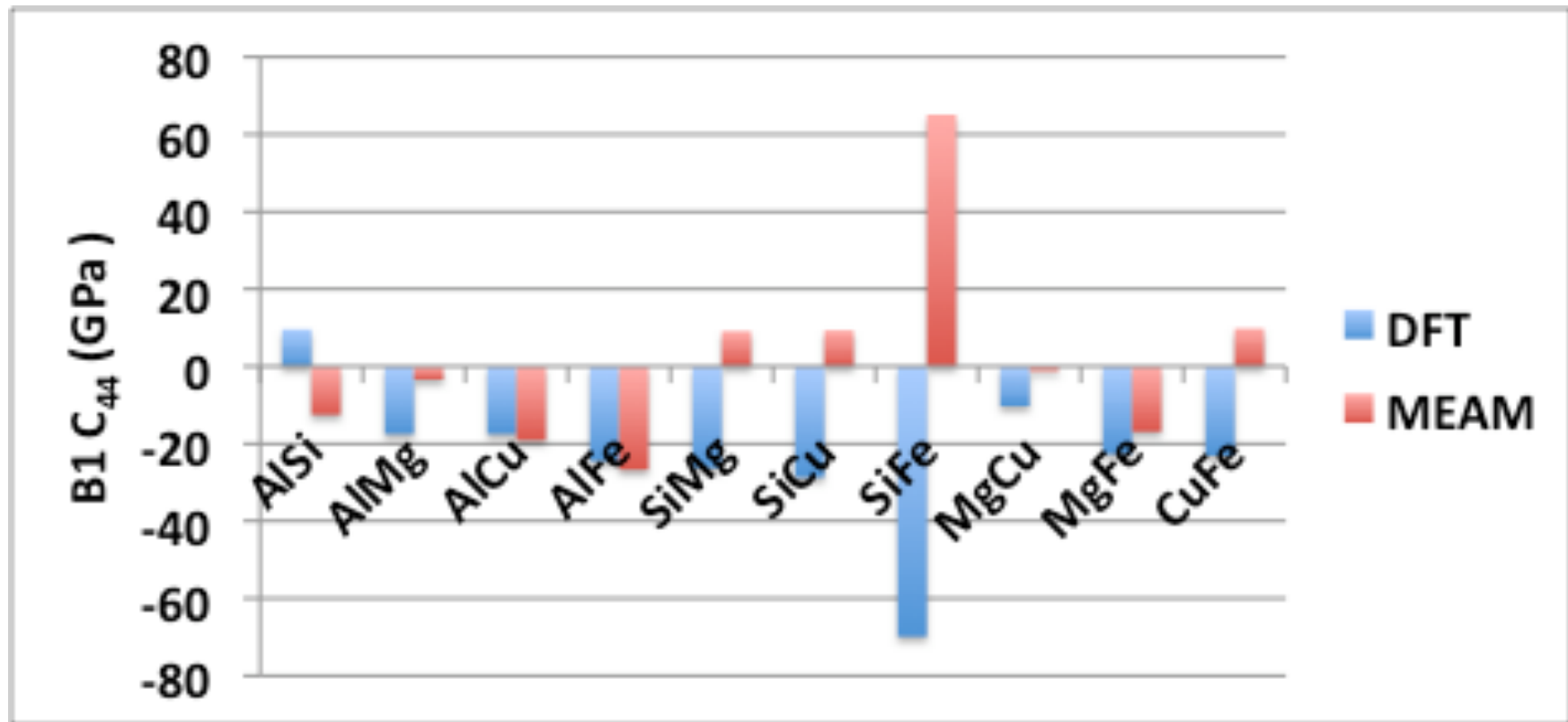
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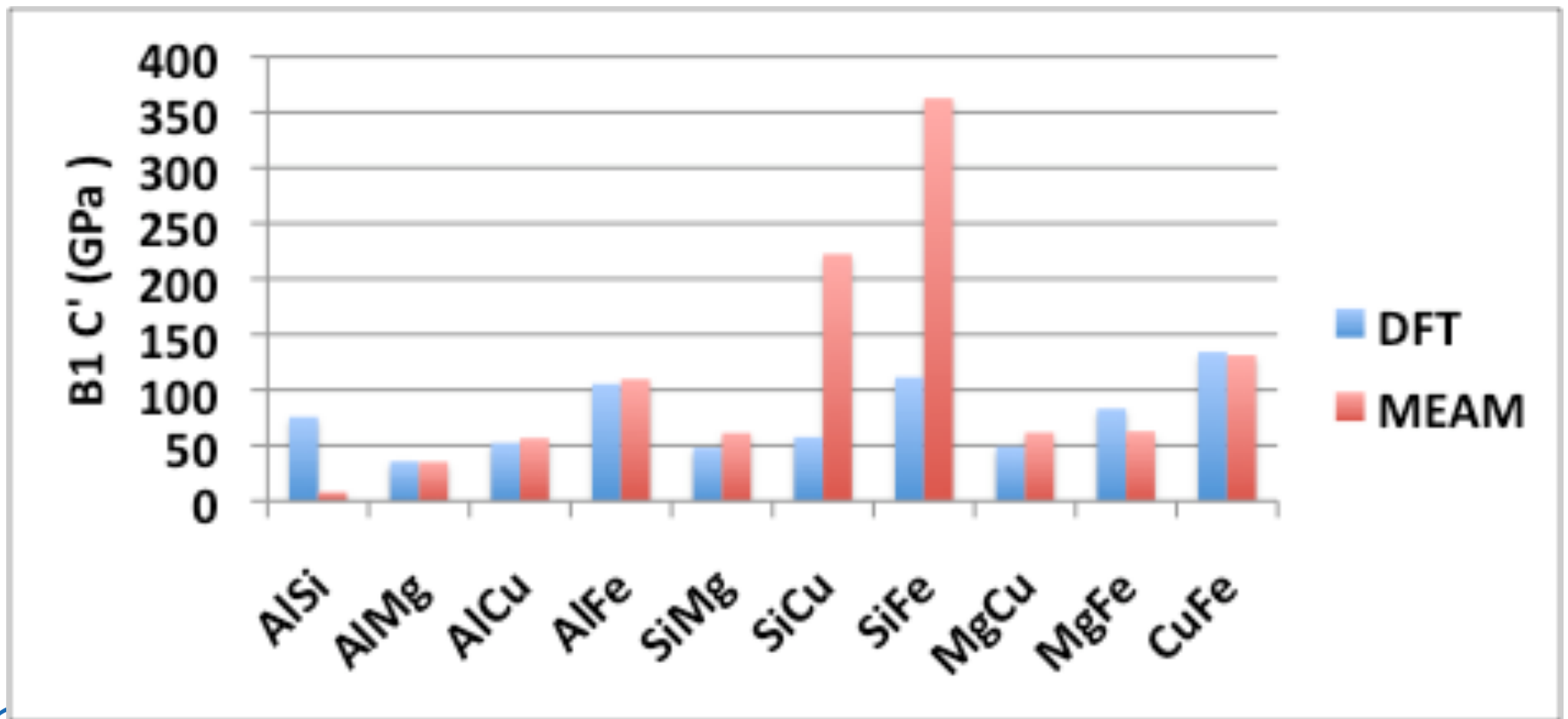
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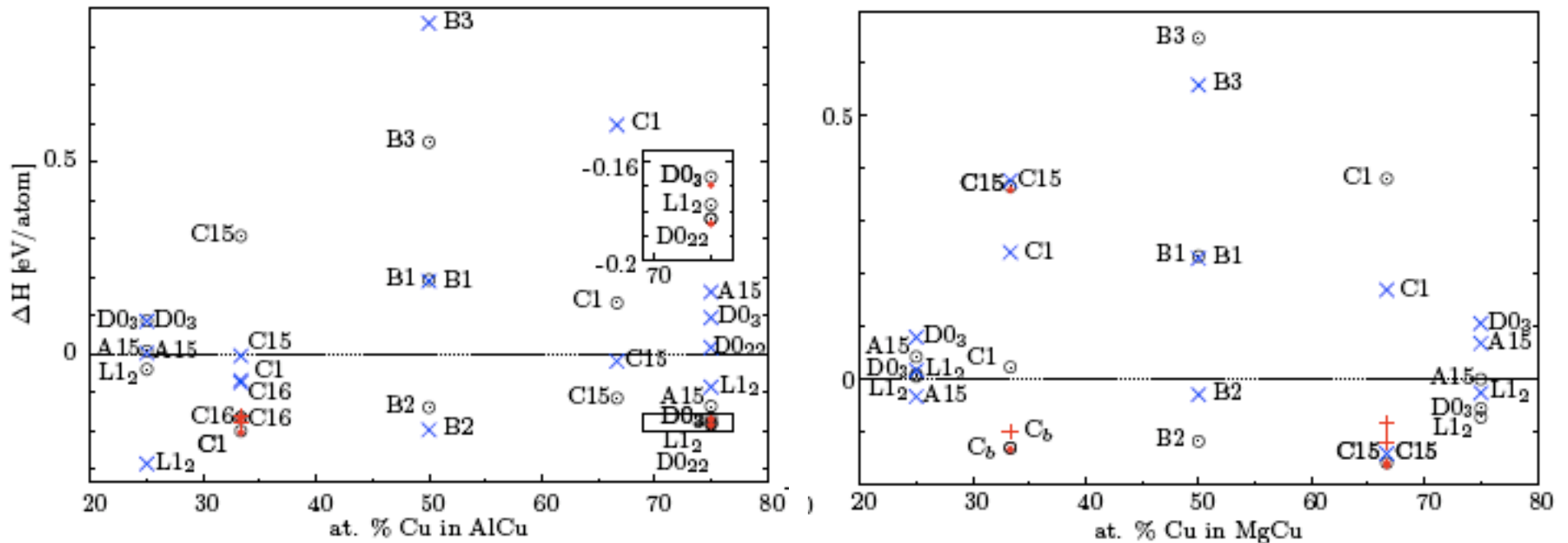
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MEAM COMPARISON TO DFT DATA BASE



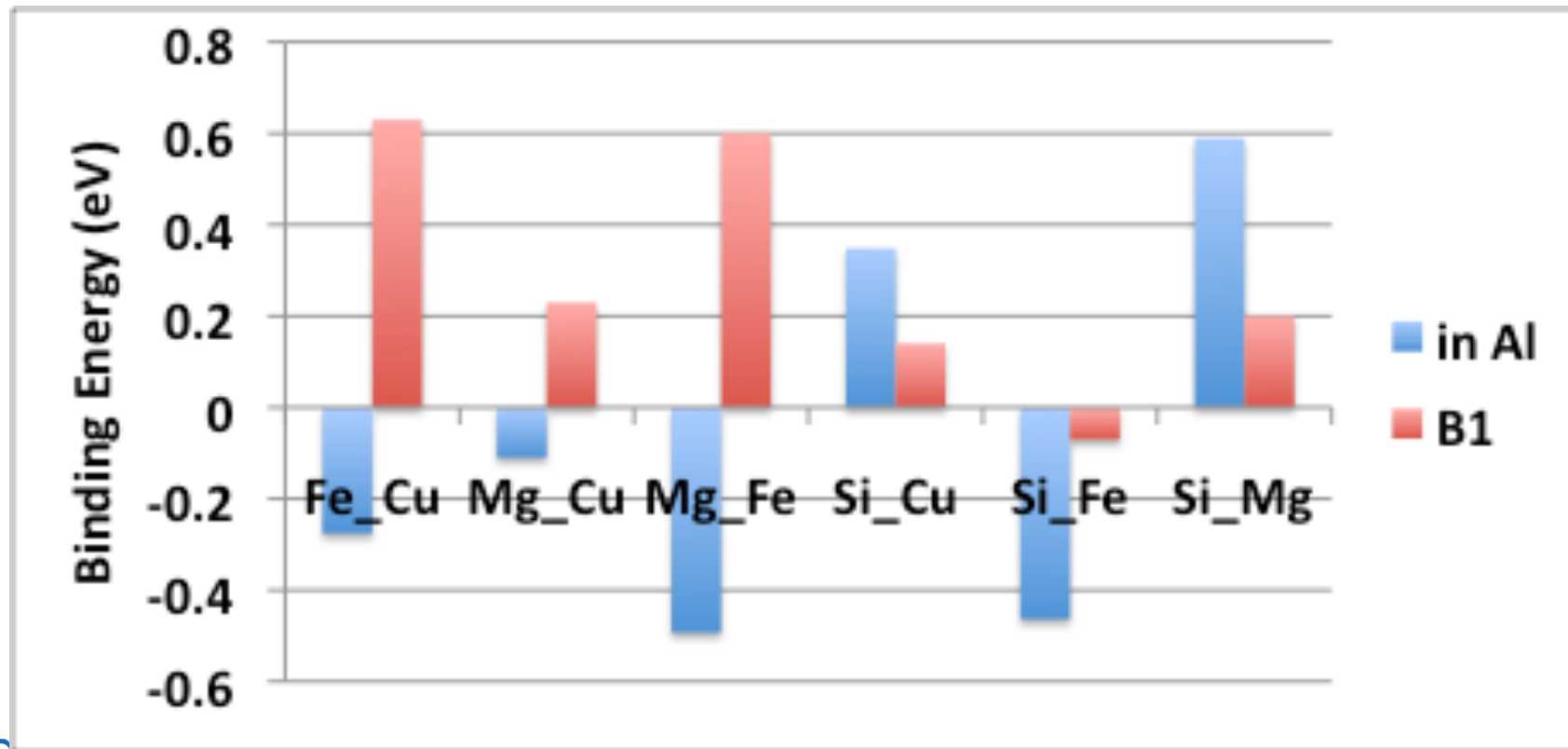
CALCULATED HEATS AGREE WITH EXPERIMENT AND DFT OVER THE ENTIRE COMPOSITION RANGE



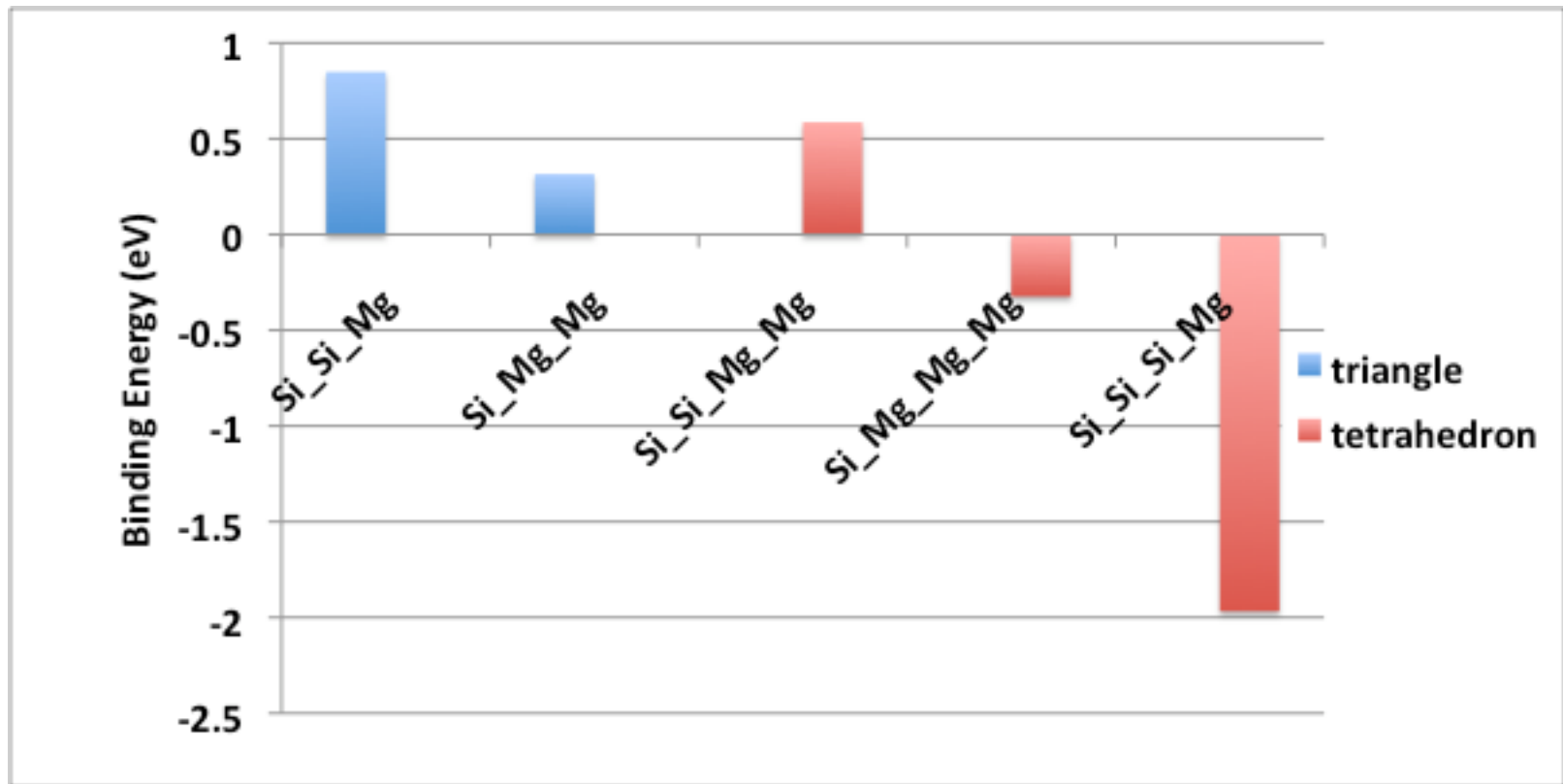
PREDICTED SOLUTION ENERGY AGREES REASONABLY WELL WITH DFT

Bulk	Substitute atom				
	Al	Si	Mg	Cu	Fe
Al		0.5 (0.5)	0.06 (0.05)	-1.1 (-0.1)	-1.2(-0.4)
Si	6.6 (0.9)		2.9 (2.4)	1.9 (2.)	1.6 (1.9)
Mg	-0.7 (0.06)	0.2 (0.4)		-0.2 (0.2)	1.5 (1.1)
Cu	0.8 (-0.7)	0.8 (-0.2)	1.1 (-0.2)		2.9 (1.4)
Fe	0.8 (-0.7)	-2.9 (-1.1)	0.8 (1.0)	-0.3 (0.8)	

BINDING OF SUBSTITUTIONAL IMPURITIES NOT REFLECTED BY B1 STABILITY



SMALL CLUSTERS OF Si AND Mg in Al ARE BOUND



SUMMARY

- **MEAM potentials were developed for a 5 component system: Al, Si, Mg, Cu, and Fe**
- **Calculations show the functions reproduce the DFT and experimental data base**
- **Small clusters of Si and Mg are shown to be stable in Al**